

TQFP, FP-BGA
Commercial Temp
Industrial Temp

64K x 24

1.5Mb Asynchronous SRAM

8, 9, 10, 12, 15 ns
3.3 V V_{DD}
Center V_{DD} and V_{SS}

Features

- Fast access time: 8, 9, 10, 12, 15 ns
- CMOS low power operation: 190/170/160/130/110 mA at minimum cycle time.
- Single 3.3 V $\pm$ 0.3 V power supply
- All inputs and outputs are TTL-compatible
- Fully static operation
- Industrial Temperature Option: -40 to 85°C
- Package
 - T: 100-pin TQFP package
 - U: 6 mm x 8 mm Fine Pitch Ball Grid Array
 - GT: RoHS-compliant 100-pin TQFP available
 - GU: RoHS-compliant 6 mm x 8 mm Fine Pitch BGA

Description

The GS71024 is a high speed CMOS static RAM organized as 65,536 words by 24 bits. Static design eliminates the need for external clocks or timing strobes. The GS71024 operates on a single 3.3 V power supply, and all inputs and outputs are TTL-compatible. The GS71024 is available in a 6 mm x 8 mm Fine Pitch BGA package, as well as in a 100-pin TQFP package.

Fine Pitch BGA Bump Configuration

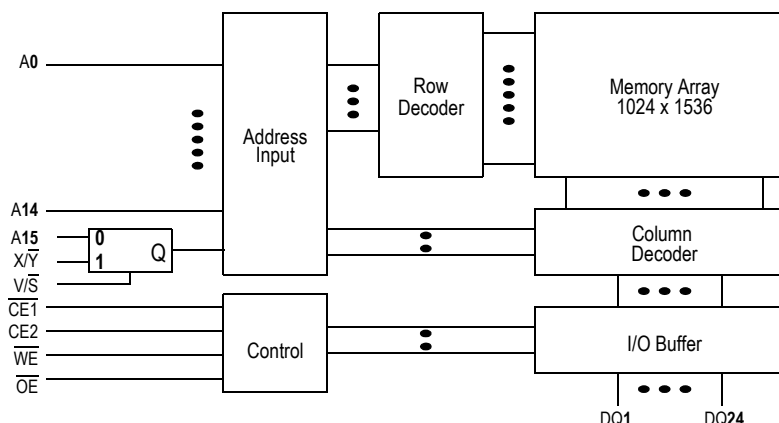
	1	2	3	4	5	6
A	DQ	A3	A2	A1	A0	DQ
B	DQ	DQ	CE2	$\overline{\text{WE}}$	DQ	DQ
C	DQ	DQ	$\overline{\text{CE1}}$	$\overline{\text{OE}}$	DQ	DQ
D	V_{SS}	DQ	A5	A4	DQ	V_{DD}
E	V_{DD}	DQ	A7	A6	DQ	V_{SS}
F	DQ	DQ	A9	A8	DQ	DQ
G	DQ	DQ	A11	A10	DQ	DQ
H	DQ	A15	A14	A13	A12	DQ

6 mm x 8 mm, 0.75 mm Bump Pitch
Top View

Pin Descriptions

Symbol	Description	Symbol	Description
A0 to A15	Address input	DQ1 to DQ24	Data input/output
X/Y	Vector Input	V/S	Address Multiplexer Control
WE	Write enable input	OE	Output enable input
CE1, CE2	Chip enable input	—	—
V_{DD}	+3.3 V power supply	V_{SS}	Ground

Block Diagram



The top view of the 74VHC04N package shows a square layout with pins numbered 1 to 50. The functions for each pin are as follows:

Pin	Function	Pin	Function
1	NC	80	NC
2	NC	79	NC
3	NC	78	NC
4	NC	77	NC
5	NC	76	NC
6	DQ	75	DQ
7	DQ	74	DQ
8	DQ	73	DQ
9	DQ	72	DQ
10	V _{SS}	71	V _{SS}
11	V _{DD}	70	V _{DD}
12	DQ	69	DQ
13	DQ	68	DQ
14	NC	67	V _{SS}
15	V _{DD}	66	NC
16	NC	65	V _{DD}
17	V _{SS}	64	NC
18	DQ	63	DQ
19	DQ	62	DQ
20	V _{DD}	61	V _{DD}
21	V _{SS}	60	V _{SS}
22	DQ	59	DQ
23	DQ	58	DQ
24	DQ	57	DQ
25	DQ	56	DQ
26	NC	55	NC
27	NC	54	NC
28	NC	53	NC
29	NC	52	NC
30	NC	51	NC
31	NC		
32	A		
33	A		
34	A		
35	A		
36	A		
37	A		
38	NC		
39	NC		
40	V _{SS}		
41	V _{DD}		
42	NC		
43	NC		
44	A		
45	A		
46	A		
47	A		
48	A		
49	A		
50	NC		

Truth Table

$\overline{\text{CE1}}$	CE2	$\overline{\text{OE}}$	$\overline{\text{WE}}$	V/S	Mode	DQ0 to DQ23	V _{DD} Current
H	X	X	X	X	Not selected	High Z	ISB1, ISB2
X	L	X	X	X	Not selected	High Z	
L	H	L	H	H	Read using $\overline{\text{X}}/\overline{\text{Y}}$	Data Out	I _{DD}
L	H	L	H	L	Read using A15	Data Out	
L	H	X	L	H	Write using $\overline{\text{X}}/\overline{\text{Y}}$	Data In	
L	H	X	L	L	Write using A15	Data In	
L	H	H	H	X	Output disable	High Z	

X: "H" or "L"

Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply Voltage	V _{DD}	−0.5 to +4.6	V
Input Voltage	V _{IN}	−0.5 to V _{DD} + 0.5 (≤ 4.6 V max.)	V
Output Voltage	V _{OUT}	−0.5 to V _{DD} + 0.5 (≤ 4.6 V max.)	V
Allowable TQFP power dissipation	PD	1	W
Allowable FPBGA power dissipation	PD	1	W
Storage temperature	T _{STG}	−55 to 150	°C

Note:

Permanent device damage may occur if Absolute Maximum Ratings are exceeded. Functional operation shall be restricted to Recommended Operating Conditions. Exposure to higher than recommended voltages for extended periods of time could affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Minimum	Typical	Maximum	Unit
Supply Voltage for -10/12/15	V_{DD}	3.0	3.3	3.6	V
Supply Voltage for -8	V_{DD}	3.135	3.3	3.6	V
Input High Voltage	V_{IH}	2.0	—	$V_{DD} + 0.3$	V
Input Low Voltage	V_{IL}	-0.3	—	0.8	V
Ambient Temperature, Commercial Range	T_{Ac}	0	—	70	°C
Ambient Temperature, Industrial Range	T_{Ai}	-40	—	85	°C

Notes:

1. Input overshoot voltage should be less than $V_{DD} + 2$ V and not exceed 20 ns.
2. Input undershoot voltage should be greater than -2 V and not exceed 20 ns.

Capacitance

Parameter	Symbol	Test Condition	Maximum	Unit
Input Capacitance	C_{IN}	$V_{IN} = 0$ V	5	pF
I/O Capacitance	C_{OUT}	$V_{OUT} = 0$ V	7	pF

Notes:

1. Tested at $T_A = 25^{\circ}\text{C}$, $f = 1$ MHz
2. These parameters are sampled and are not 100% tested

DC I/O Pin Characteristics

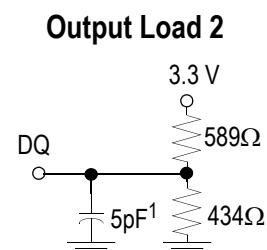
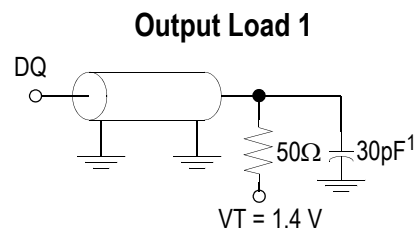
Parameter	Symbol	Test Conditions	Minimum	Maximum
Input Leakage Current	I_{IL}	$V_{IN} = 0$ to V_{DD}	-1uA	1uA
Output Leakage Current	I_{OL}	Output High Z, $V_{OUT} = 0$ to V_{DD}	-1uA	1uA
Output High Voltage	V_{OH}	$I_{OH} = -4\text{mA}$	2.4	—
Output Low Voltage	V_{OL}	$I_{OL} = +4\text{mA}$	—	0.4 V

AC Test Conditions

Parameter	Conditions
Input high level	$V_{IH} = 2.4 \text{ V}$
Input low level	$V_{IL} = 0.4 \text{ V}$
Input rise time	$t_r = 1 \text{ V/ns}$
Input fall time	$t_f = 1 \text{ V/ns}$
Input reference level	1.4 V
Output reference level	1.4 V
Output load	Fig. 1 & 2

Notes:

1. Include scope and jig capacitance.
2. Test conditions as specified with output loading as shown in **Fig. 1** unless otherwise noted
3. Output load 2 for t_{LZ} , t_{HZ} , t_{OLZ} and t_{OHZ} .



Power Supply Currents

Parameter	Symbol	Test Conditions	0 to 70°C					-40 to 85°C		
			8 ns	9 ns	10 ns	12 ns	15 ns	10 ns	12 ns	15 ns
Operating Supply Current	I_{DD}	$\overline{CE} \leq V_{IL}$ All other inputs $\geq V_{IH}$ or $\leq V_{IL}$ Min. cycle time $I_{OUT} = 0 \text{ mA}$	190 mA	170 mA	160 mA	130 mA	110 mA	165 mA	135 mA	115 mA
Standby Current	I_{SB1}	$\overline{CE} \geq V_{IH}$ All other inputs $\geq V_{IH}$ or $\leq V_{IL}$ Min. cycle time	45 mA	45 mA	40 mA	35 mA	30 mA	45 mA	40 mA	35 mA
Standby Current	I_{SB2}	$CE \geq V_{DD} - 0.2 \text{ V}$ All other inputs $\geq V_{DD} - 0.2 \text{ V}$ or $\leq 0.2 \text{ V}$	10 mA					15 mA		

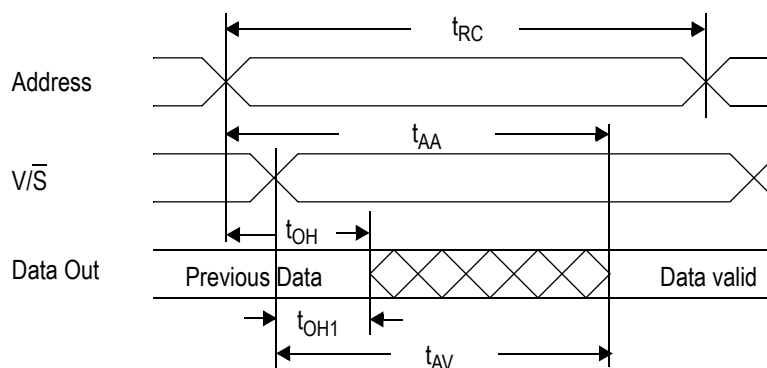
AC Characteristics

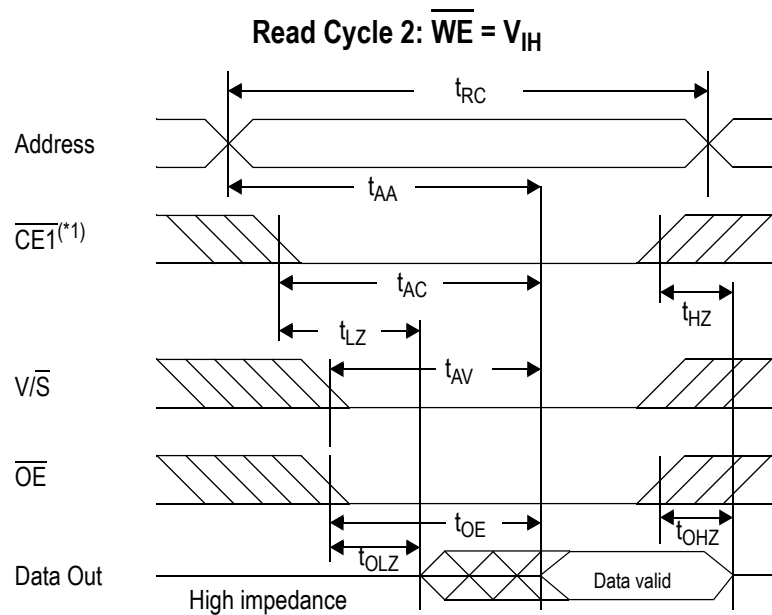
Read Cycle

Parameter	Symbol	-8		-9		-10		-12		-15		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
Read cycle time	t_{RC}	8	—	9	—	10	—	12	—	15	—	ns
Address access time	t_{AA}	—	8	—	9	—	10	—	12	—	15	ns
Chip enable access time ($\overline{CE1}$, CE2)	t_{AC}	—	8	—	9	—	10	—	12	—	15	ns
MUX control to output valid ($V/\overline{S}$)	t_{AV}	—	8	—	9	—	10	—	12	—	15	ns
Output enable to output valid ($\overline{OE}$)	t_{OE}	—	4	—	4.5	—	5	—	6	—	7	ns
Output hold from address change	t_{OH}	3	—	3	—	3	—	3	—	3	—	ns
Output hold from MUX controls change	t_{OH1}	3	—	3	—	3	—	3	—	3	—	ns
Chip enable to output in low Z ($\overline{CE1}$, CE2)	t_{LZ}^*	3	—	3	—	3	—	3	—	3	—	ns
Output enable to output in low Z ($\overline{OE}$)	t_{OLZ}^*	0	—	0	—	0	—	0	—	0	—	ns
Chip disable to output in High Z ($\overline{CE1}$, CE2)	t_{HZ}^*	—	4	—	4.5	—	5	—	6	—	7	ns
Output disable to output in High Z ($\overline{OE}$)	t_{OHZ}^*	—	4	—	4.5	—	5	—	6	—	7	ns

* These parameters are sampled and are not 100% tested

Read Cycle 1: $\overline{CE} = \overline{OE} = V_{IL}$, $\overline{WE} = V_{IH}$





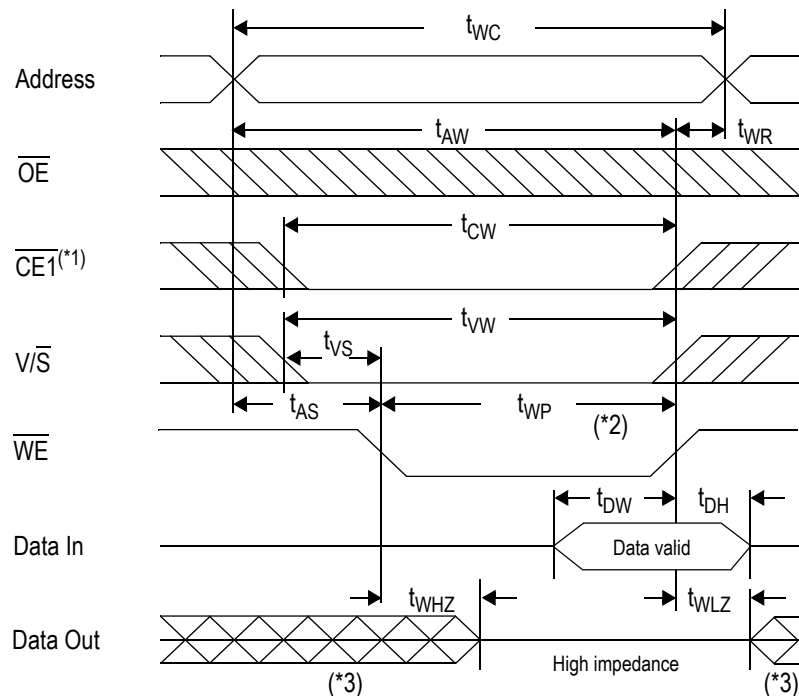
*1 $\overline{CE1}$ represents both $\overline{CE1}$ low and CE2 high.

Write Cycle

Parameter	Symbol	-8		-9		-10		-12		-15		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
Write cycle time	t_{WC}	8	—	9	—	10	—	12	—	15	—	ns
Address valid to end of write	t_{AW}	5.5	—	6.25	—	7	—	8	—	10	—	ns
Chip enable to end of write ($\overline{CE1}$, CE2)	t_{CW}	5.5	—	6.25	—	7	—	8	—	10	—	ns
MUX control to end of write ($V/\overline{S}$)	t_{VW}	5.5	—	6.25	—	7	—	8	—	10	—	ns
Data set up time	t_{DW}	4	—	4.5	—	5	—	6	—	7	—	ns
Data hold time	t_{DH}	0	—	0	—	0	—	0	—	0	—	ns
Write pulse width	t_{WP}	5.5	—	6.25	—	7	—	8	—	10	—	ns
Address set up time	t_{AS}	0	—	0	—	0	—	0	—	0	—	ns
MUX control set up time	t_{VS}	0	—	0	—	0	—	0	—	0	—	ns
Write recovery time ($\overline{WE}$)	t_{WR}	0	—	0	—	0	—	0	—	0	—	ns
Write recovery time ($V/\overline{S}$, $\overline{CE1}$, CE2)	t_{WR1}	0	—	0	—	0	—	0	—	0	—	ns
Output Low Z from end of write	t_{WLZ}^*	2	—	2.5	—	3	—	3	—	3	—	ns
Write to output in High Z	t_{WHZ}^*	—	4	—	4.5	—	5	—	6	—	7	ns

* These parameters are sampled and are not 100% tested

Write Cycle 1: $\overline{WE}$ control

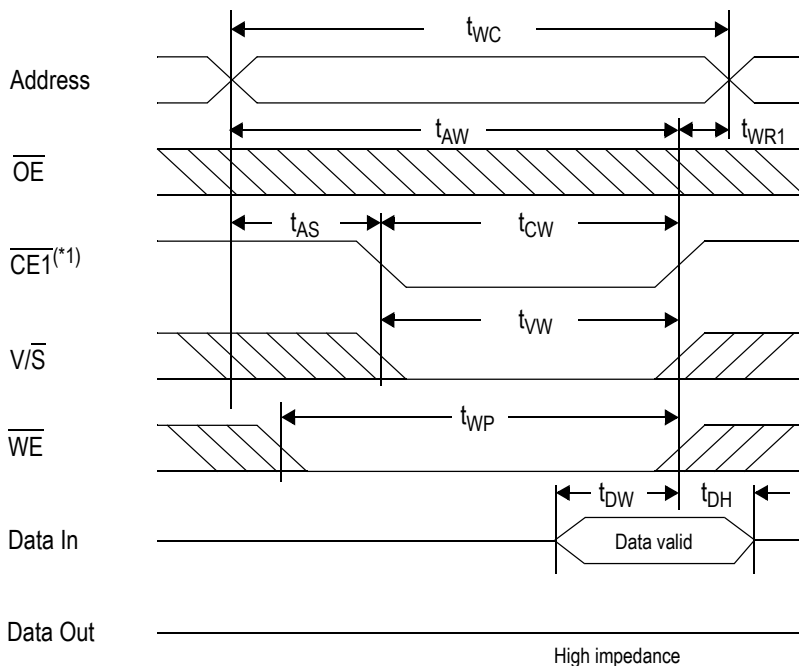


*1 $\overline{CE1}$ represents both $\overline{CE1}$ low and $CE2$ high.

*2 Write is executed when both $\overline{CE1}$ and $\overline{WE}$ are at low simultaneously.

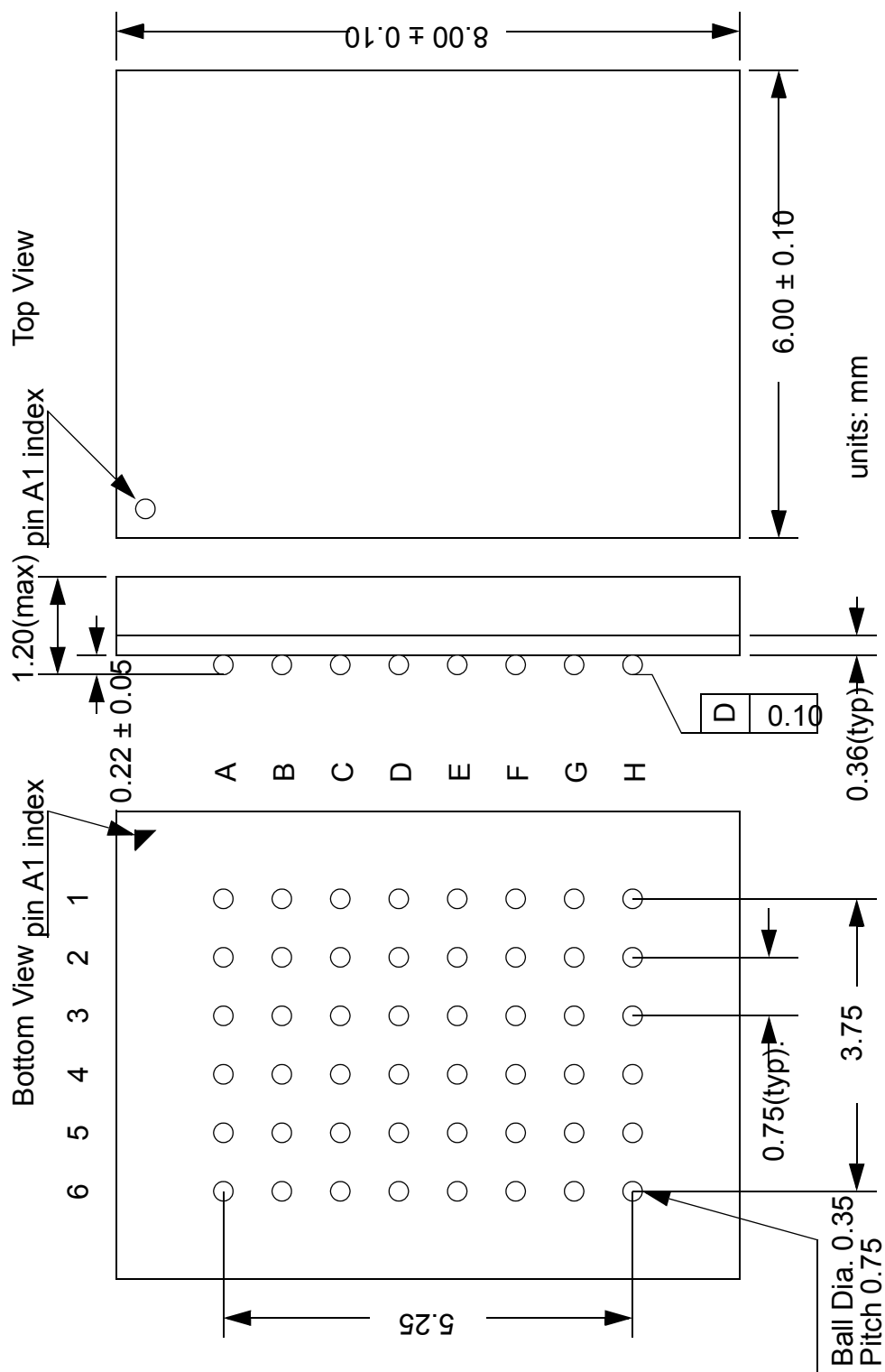
*3 Do not apply the data input voltage to the output while DQ pin is in output condition.

Write Cycle 2: $\overline{CE}$ control



*1 $\overline{CE1}$ represents both $\overline{CE1}$ low and $CE2$ high.

6 mm x 8 mm Fine Pitch BGA

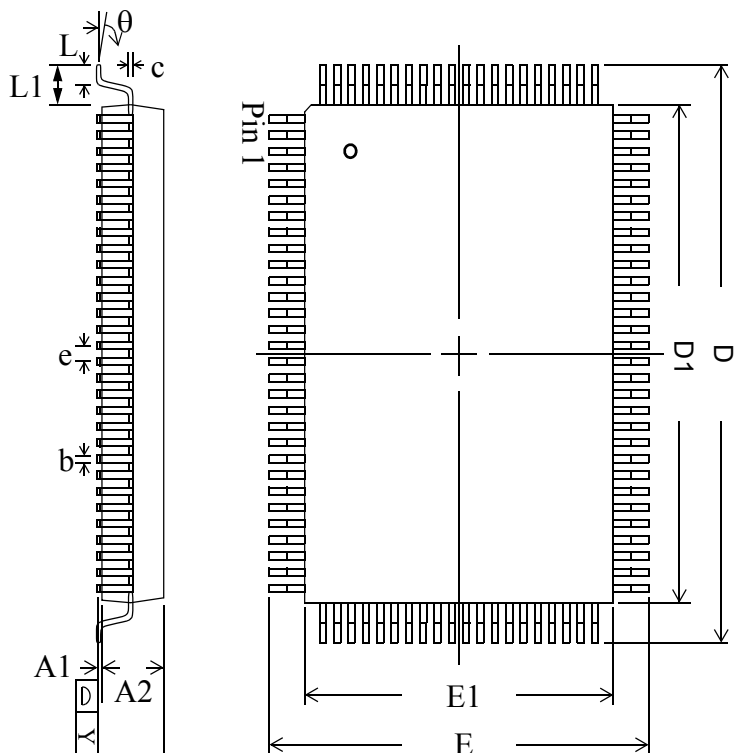


TQFP Package Drawing

Symbol	Description	Min.	Nom.	Max
A1	Standoff	0.05	0.10	0.15
A2	Body Thickness	1.35	1.40	1.45
b	Lead Width	0.20	0.30	0.40
c	Lead Thickness	0.09		0.20
D	Terminal Dimension	21.9	22.0	22.1
D1	Package Body	19.9	20.0	20.1
E	Terminal Dimension	15.9	16.0	16.1
E1	Package Body	13.9	14.0	14.1
e	Lead Pitch		0.65	
L	Foot Length	0.45	0.60	0.75
L1	Lead Length		1.00	
Y	Coplanarity			0.10
θ	Lead Angle	0°		7°

Notes:

1. All dimensions are in millimeters (mm).
2. Package width and length do not include mold protrusion



BPR 1999.05.18

Ordering Information

Part Number	Package	Access Time	Temp. Range	Status
GS71024T-8	100-Pin TQFP	8 ns	Commercial	MP
GS71024T-9	100-Pin TQFP	9 ns	Commercial	MP
GS71024T-10	100-Pin TQFP	10 ns	Commercial	MP
GS71024T-12	100-Pin TQFP	12 ns	Commercial	MP
GS71024T-15	100-Pin TQFP	15 ns	Commercial	MP
GS71024T-8I	100-Pin TQFP	8 ns	Industrial	MP
GS71024T-9I	100-Pin TQFP	9 ns	Industrial	MP
GS71024T-10I	100-Pin TQFP	10 ns	Industrial	MP
GS71024T-12I	100-Pin TQFP	12 ns	Industrial	MP
GS71024T-15I	100-Pin TQFP	15 ns	Industrial	MP
GS71024GT-8	RoHS-compliant 100-Pin TQFP	8 ns	Commercial	PQ
GS71024GT-9	RoHS-compliant 100-Pin TQFP	9 ns	Commercial	PQ
GS71024GT-10	RoHS-compliant 100-Pin TQFP	10 ns	Commercial	PQ
GS71024GT-12	RoHS-compliant 100-Pin TQFP	12 ns	Commercial	PQ
GS71024GT-15	RoHS-compliant 100-Pin TQFP	15 ns	Commercial	PQ
GS71024GT-8I	RoHS-compliant 100-Pin TQFP	8 ns	Industrial	PQ
GS71024GT-9I	RoHS-compliant 100-Pin TQFP	9 ns	Industrial	PQ
GS71024GT-10I	RoHS-compliant 100-Pin TQFP	10 ns	Industrial	PQ
GS71024GT-12I	RoHS-compliant 100-Pin TQFP	12 ns	Industrial	PQ
GS71024GT-15I	RoHS-compliant 100-Pin TQFP	15 ns	Industrial	PQ
GS71024U-8	6 mm x 8 mm Fine Pitch BGA	8 ns	Commercial	MP
GS71024U-9	6 mm x 8 mm Fine Pitch BGA	9 ns	Commercial	MP
GS71024U-10	6 mm x 8 mm Fine Pitch BGA	10 ns	Commercial	MP
GS71024U-12	6 mm x 8 mm Fine Pitch BGA	12 ns	Commercial	MP
GS71024U-15	6 mm x 8 mm Fine Pitch BGA	15 ns	Commercial	MP
GS71024U-8I	6 mm x 8 mm Fine Pitch BGA	8 ns	Industrial	MP
GS71024U-9I	6 mm x 8 mm Fine Pitch BGA	9 ns	Industrial	MP
GS71024U-10I	6 mm x 8 mm Fine Pitch BGA	10 ns	Industrial	MP
GS71024U-12I	6 mm x 8 mm Fine Pitch BGA	12 ns	Industrial	MP

Ordering Information

Part Number	Package	Access Time	Temp. Range	Status
GS71024U-15I	6 mm x 8 mm Fine Pitch BGA	15 ns	Industrial	MP
GS71024GU-8	RoHS-compliant 6 mm x 8 mm Fine Pitch BGA	8 ns	Commercial	PQ
GS71024GU-9	RoHS-compliant 6 mm x 8 mm Fine Pitch BGA	9 ns	Commercial	PQ
GS71024GU-10	RoHS-compliant 6 mm x 8 mm Fine Pitch BGA	10 ns	Commercial	PQ
GS71024GU-12	RoHS-compliant 6 mm x 8 mm Fine Pitch BGA	12 ns	Commercial	PQ
GS71024GU-15	RoHS-compliant 6 mm x 8 mm Fine Pitch BGA	15 ns	Commercial	PQ
GS71024GU-8I	RoHS-compliant 6 mm x 8 mm Fine Pitch BGA	8 ns	Industrial	PQ
GS71024GU-9I	RoHS-compliant 6 mm x 8 mm Fine Pitch BGA	9 ns	Industrial	PQ
GS71024GU-10I	RoHS-compliant 6 mm x 8 mm Fine Pitch BGA	10 ns	Industrial	PQ
GS71024GU-12I	RoHS-compliant 6 mm x 8 mm Fine Pitch BGA	12 ns	Industrial	PQ
GS71024GU-15I	RoHS-compliant 6 mm x 8 mm Fine Pitch BGA	15 ns	Industrial	PQ

Notes:

- Customers requiring Tape and Reel should add the character "T" to the end of the part number. For example: GS71024T/U-12T.
- MP = Mass Production. PQ = Pre-Qualification.

Revision History

Rev. Code: Old; New	Types of Changes Format or Content	Page/Revisions/Reason
GS71024Rev 2:17pm, 4/8/ 1999; 1.00a5/1999	Format/Typos	• Document Changed subscripts to small caps. • 1/Features: Changed TP to T. • Document/Replaced “micro” with “fine pitch”.
	Content	• Ordering Information/Added Tape and Reel Note/Enhancement • Pin Description/Changed A0 - A14 to A0 - A15/Correction • Page 1/Took out “Byte Control” from Features/Correction • 3/Changed pin 97 from NC to CE2/Correction
GS710241.00a5/1999; 1.01 8/1999B	Content	1. Pin out/Changed Pin 89 from CK to NC/Correction 2. Pin out/Changed Pin 92 from NC to V/$\bar{S}$/Correction 3. Pin out/Changed Pin 93 from V/$\bar{S}$ to X/$\bar{Y}$/Correction 4. Pin out/Changed Pin 94 from X/$\bar{Y}$ to NC/Correction
GS710241.01 8/1999C; 1.02 9/1999C	Content	• Package Diagram/Changed Dimension “D Max” from 20.1 to 22.1/Correction
GS71024Rev1.01 8/ 1999C;Rev1.02 2/2000D	Format	• GSI Logo
Rev1.02 2/2000D; 71024_r1_03	Format and Content	• Updated format to comply with Technical Publications standards • Changed all V_{SSQ} to V_{SS} and all V_{DDQ} to V_{DD} in pinout on page 2 • Updated Revision History (revision notes for 8/1999 incorrect)
71024_r1_03; 71024_r1_04	Content	• Added 9 ns references to entire document
71024_r1_04; 71024_r1_05	Content/Format	• Updated format • Added Pb-free information for TQFP package
71024_r1_05; 71024_r1_06	Content	• Changed Pb-free information to RoHS-compliant • Added RoHS-compliant information for BGA package